

Photo DMOS-FET Relay

Description

The **LT339** is a miniature 2-Form A solid state relay in a 8 pin SOP package featuring low C×R .That employs optically coupled MOSFET technology to provide 1500V of input to output isolation. The optically coupled input is controlled by a highly efficient GaAlAs infrared LED and MOS FETs on the output side.

Features

- SOP package 8 Pin type in miniature design (4.4×9.4×2.0mm / .173×.37×.083inch)
- Low driver power requirements (TTL/CMOS Compatible)
- Low CxR . Output capacitance=28pF(Typ.)
- On-Resistance=0.8Ω(Typ.) , Off-State leakage current= 1nA(Typ.)
- No moving parts ,High reliability
- Arc-Free with no snubbing circuits
- 1500Vrms Input/Output isolation
- Tape & Reel version available

Applications

- Telecommunications (PC, Electronic notepad)
- Measuring and Testing equipment
- Industrial control
- Security equipments
- High speed inspection machine

Outline Dimensions

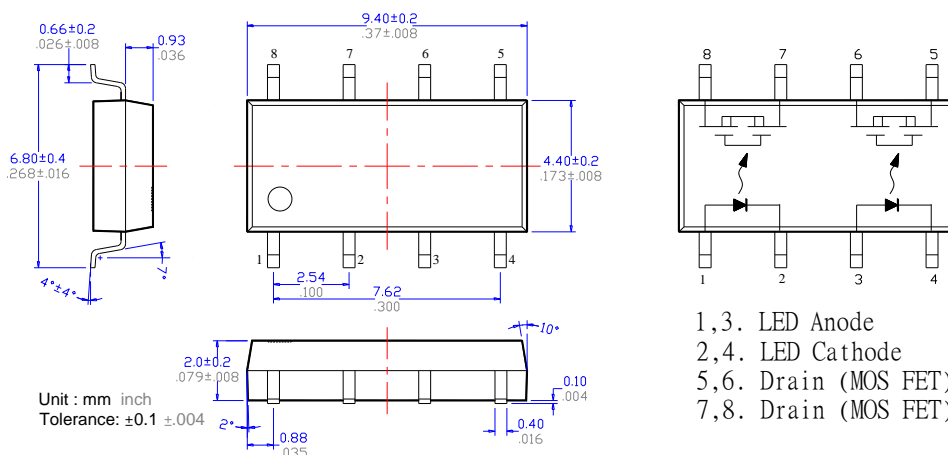


Photo DMOS-FET Relay Specifications

Part Name: LT339

(Load voltage: 60V / Load current: 500mA)

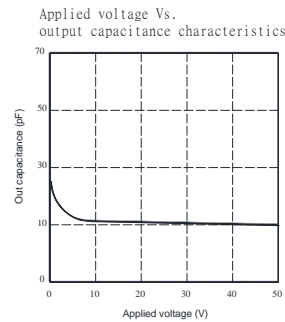
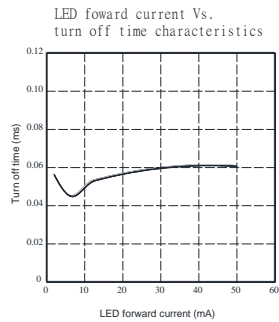
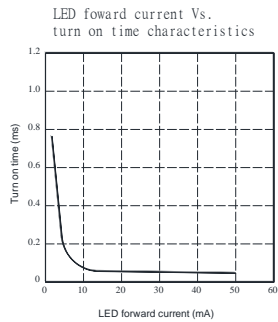
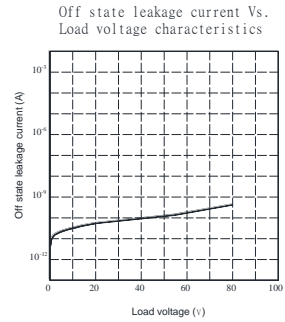
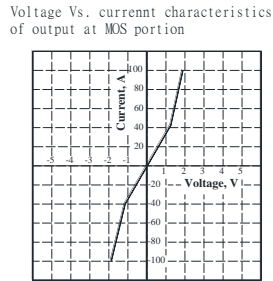
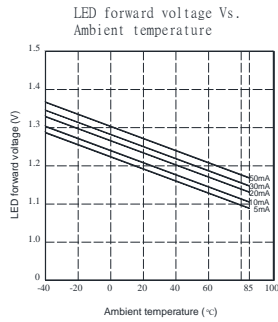
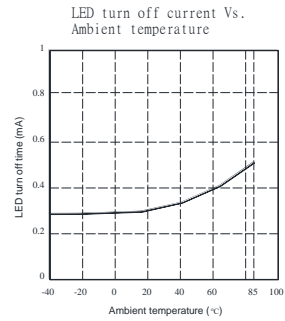
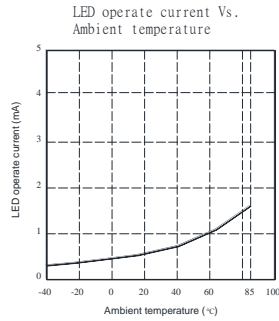
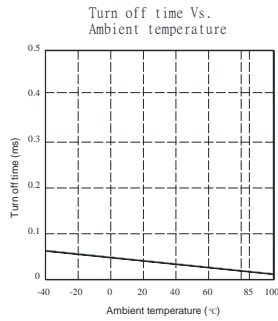
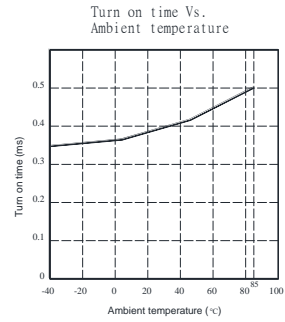
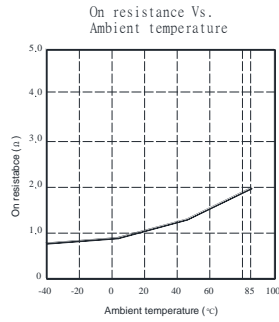
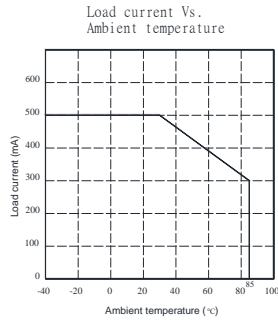
Absolute Maximum Ratings (Ambient Temperature: 25°C)

Item	Symbol	Value	Units	Note	
Input	Continuous LED Current	I _F	50	mA	
	Peak LED Current	I _{FP}	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	V _R	5	V	
	Input Power Dissipation	P _{In}	75	mW	
Output	Load Voltage	V _L	60	V(AC peak or DC)	
	Load Current	I _L	500	mA	
	Peak Load Current	I _{Peak}	1.5	A	100ms(1 pulse)
	Output Power Dissipation	P _{Out}	450	mW	
Total Power Dissipation	P _T	500	mW		
I/O Breakdown Voltage	V _{I/O}	1500	V _{rms}	RH=60%, 1min	
Operating Temperature	T _{opr}	-40 to +85	°C		
Storage Temperature	T _{stg}	-40 to +100	°C		
Pin Soldering Temperature	T _{sol}	260	°C	10 sec max.	

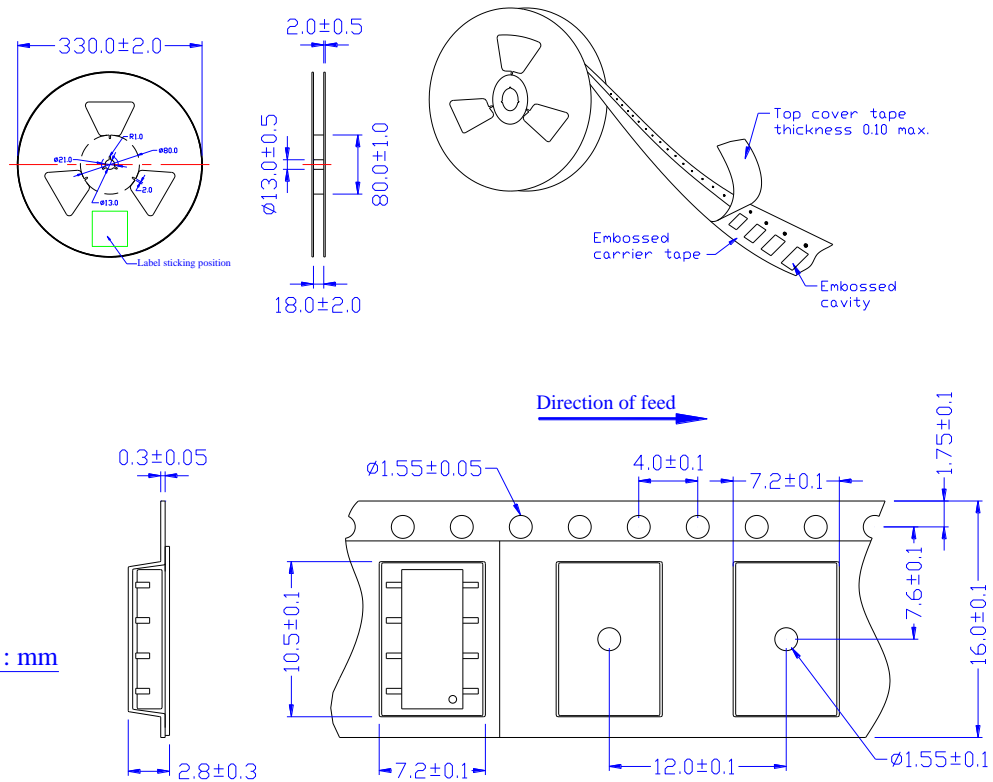
Electrical Specifications (Ambient Temperature: 25°C)

Item	Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	V _F	1.2	1.4	V	I _F =10mA
	Operation LED Current	I _{Fon}	0.8	2.0	mA	
	Recovery LED Current	I _{Foff}	0.35	0.5	mA	
	Recovery LED Voltage	V _{Foff}	0.7		V	
Output	On-Resistance	R _{on}	0.8	2	Ω	I _F =5mA, I _L =100mA, Time to flow is within 1 sec.
	Off-State Leakage Current	I _{Leak}	0.5	1.0	uA	V _L =Rating
	Output Capacitance	C _{out}	28		pF	V _L =0, f=1MHz
Transmis sion	Turn-On Time	T _{on}	0.35	0.5	ms	I _F =5mA, I _L =100mA,
	Turn-Off Time	T _{off}	0.2	0.3	ms	
Coupled	I/O Isolation Resistance	R _{I/O}	10 ¹⁰		Ω	DC500V
	I/O Capacitance	C _{I/O}	0.8	1.5	pF	f=1MHz

Reference Data



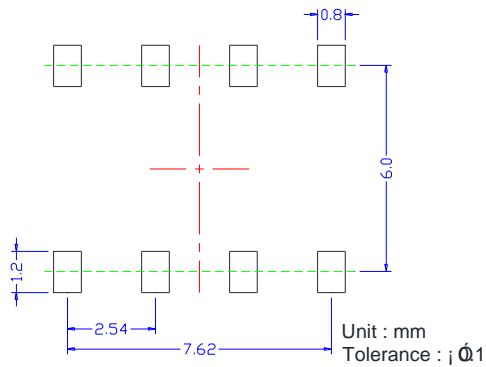
Taping Specifications for Surface Mount Devices



Unit : mm

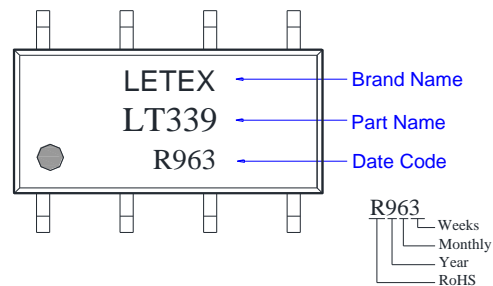
Recommended Mounting Pad

(Top view)



Marking

(Each photo MOS Relay shall be marked with the following information)



- Note: 1. There shall be leader of 230 mm minimum which may consist of carrier and or cover tape follower by a minimum of 160 mm of carrier tape sealed with cover tape.
2. There shall be a minimum of 160 mm of empty component pockets sealed with cover tape.
3. Devices are pockets in accordance with EIA standard EIA-481-A and specifications given above.
4. Packaging: 1,000pcs per reel, 2 reel per box, 5 boxes per carton.